NSN 5962-01-310-3160

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View Online at https://aerobasegroup.com/nsn/5962-01-310-3160

Overall Length:
1.420 inches
Overall Height:
0.455 inches
Overall Width:
0.620 inches
Body Length:
1.420 inches
Body Width:
0.604 inches
Body Height:
0.280 inches
Maximum Power Dissipation Rating:
135.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
1430-01-286-1314 guided missle
Features Provided:
Burn in and high performance and high speed and low power and asynchronous and 3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
24 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Memory Device Type:
Rom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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